

Monolithic Amplifier PGA-106R-75+

75Ω 5 to 250 MHz

THE BIG DEAL

- 5V/3V operation
- High IP3, 45 dBm typ. at 2 GHz, Vd=5V
- · Low Noise Figure, 0.6 at 1 GHz; 0.9 dB at 2 GHz
- Gain, 11.0 dB typ. at 2 GHz
- P1dB 22.5 dBm typ. at 2 GHz at Vd=5V
- Protected under US Patent 8,803,612



Generic photo used for illustration purposes only

CASE STYLE: DF782

+RoHS Compliant

The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

APPLICATIONS

CATV Return path

PRODUCT OVERVIEW

PGA-106R-75+ (RoHS compliant) is an advanced 75 ohm amplifier fabricated using E-PHEMT technology and offers extremely high dynamic range over a broad frequency range with low noise figure and flat gain. Lead finish is SnAgNi. It has repeatable performance from lot to lot and is enclosed in a SOT-89 package for very good thermal performance.

KEY FEATURES

| Feature | Advantages | |
|---|--|--|
| Broad Band: 5 to 250 MHz | Broadband covering CATV return path applications. | |
| High IP3 Versus DC power Consumption: 34 dBm typical | The PGA-106R-75+ matches industry leading IP3 performance relative to device size and power consumption. The combination of the design and E-PHEMPT structure provides enhanced linearity over a broad frequency range as evidence in the IP3 being typically 15 dB above the P 1dB point. This feature makes this amplifier ideal for use in CATV applications. | |
| High IP2, 62 dBm | Suppresses second order product on wideband applications such as CATV | |
| Low Noise Figure: 3.3 dB at 50 - 250 MHz 6.0 dB at 10 MHz | Low noise figure performance in combination with the high output IP3 results in high dynamic range. | |

REV. B ECO-011959 PGA-106R-75+ TH/RS/CP 220214





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ELECTRICAL SPECIFICATIONS⁽¹⁾ AT 25°C, 75Ω AND 5.0V, UNLESS NOTED OTHERWISE

| Parameter | Condition (MHz) | Min. | Тур. | Max. | Units |
|---|-----------------|------|------|------|-------|
| Frequency Range | | 5 | | 250 | MHz |
| Gain | 5 - 250 | 16.3 | 17.9 | 19.9 | dB |
| Gain Flatness (±) | 5 - 250 | | 0.1 | | dB |
| Input Return Loss | 5 - 250 | | 15.3 | | dB |
| Output Return Loss | 5 - 250 | | 19.0 | | dB |
| Reverse Isolation | 5 - 250 | | 23.4 | | dB |
| Output Power @ 1dB compression | 5 - 250 | | 19.5 | | dBm |
| Output IP3 | 5 - 250 | | 34.4 | | dBm |
| Output IP2 (2) | 5 - 250 | | 62.0 | | dBm |
| | 10 | _ | 6.0 | _ | |
| Noise Figure | 50 | _ | 3.3 | _ | dB |
| | 250 | _ | 3.1 | _ | |
| Device Operating Voltage (Vd) | | 4.8 | 5.0 | 5.2 | V |
| Device Operating Current | | _ | 116 | 132 | mA |
| Device Current Variation vs. Temperature ⁽⁴⁾ | | | 97 | | μΑ/°C |
| Device Current Variation vs Voltage | | | 0.05 | | mA/mV |
| Thermal Resitance ⁽³⁾ | | | 76 | | °C/W |

⁽¹⁾ Measured on Mini-Circuits Characterization Test board TB-587+. See Characterization Test Circuit (Fig. 1)

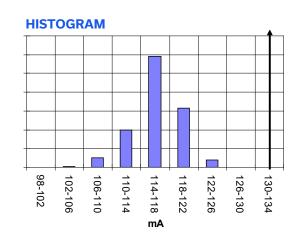
(2) Output IP2 measured at sum frequency of the two tones (f meas= f1+f2). (3) Junction to ground lead.

(4) (Current at 85°C - Current at -45°C)/130

MAXIMUM RATINGS

| Parameter | Ratings | |
|-------------------------------------|---|--|
| Operating Temperature (ground lead) | -40°C to 85°C | |
| Storage Temperature | -65°C to 150°C | |
| Operating Current at 5.0V | 170 mA | |
| Power Dissipation | 0.85 W | |
| Input Power (CW) | +23 dBm (5 minutes) +14 dBm (continuous) | |
| DC Voltage on Pin 3 | 6 V | |

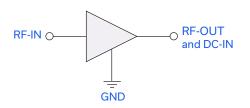
Permanent damage may occur if any of these limits are exceeded. Electrical maximum ratings are not intended for continuous normal operation.





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SIMPLIFIED SCHEMATIC AND PIN DESCRIPTION





| Function | Pin Number | Description | |
|------------------|------------|---|--|
| RF-IN | 1 | RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation. | |
| RF-OUT and DC-IN | 3 | RF output and bias pin. DC voltage is present on this pin; therefore a DC blocking capacitor is necessary for proper operation. An RF choke is needed to feed DC bias without loss of RF signal due to the bias connection, as shown in "Recommended Application Circuit", Fig. 2 | |
| GND | 2,4 | Connections to ground. Use via holes as shown in "Suggested Layout for PCB Design" to reduce ground path inductance for best performance. | |

^{*}Enhanced mode pseudomorhic High Electron Mobility Transistor.



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CHARACTERIZATION TEST CIRCUIT

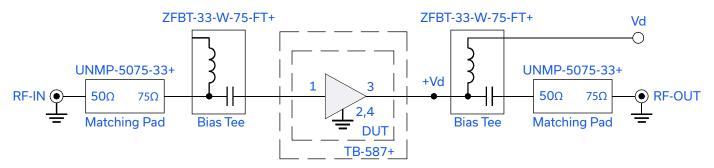


Fig 1. Block Diagram of Test Circuit used for characterization. (DUT tested on Mini-Circuits Characterization test board TB-587+)
Gain, Return loss, Output power at 1dB compression (P1 dB), output IP3 (OIP3), output IP2 (OIP2) and noise figure measured using Agilent's N5242A PNA-X microwave network analyzer.

Conditions:

- 1. Gain and Return loss: Pin= -25dBm
- 2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, 5 dBm/tone at output.
- 3. Output IP2 (OIP2): Two tones, spaced 1 MHz apart, 5 dBm/tone at output.

RECOMMENDED APPLICATION CIRCUIT

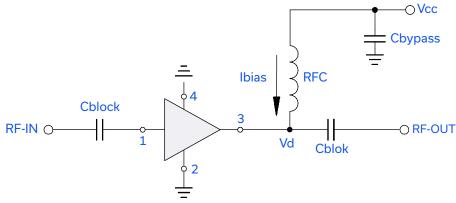
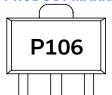


Fig 2. Evaluation board includes case, connectors, and components soldered to PCB

PRODUCT MARKING



Marking may contain other features or characters for internal lot control



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ADDITIONAL DETAILED TECHNICAL INFORMATION IS AVAILABLE ON OUR DASH BOARD. TO ACCESS CLICK HERE

| | Data Table |
|--|---|
| Performance Data | Swept Graphs |
| | S-Parameter (S2P Files) Data Set (.zip file) |
| Case Style | DF782 (SOT 89) Plastic package, exposed paddle lead finish: tin-silver over nickel |
| Tape & Reel Standard quantities available on reel | F55 7" reels with 20, 50, 100, 200, 500 or 1K devices |
| Suggested Layout for PCB Design | PL-384 |
| Evaluation Board | TB-699+ |
| Environmental Ratings | ENV08T1 |

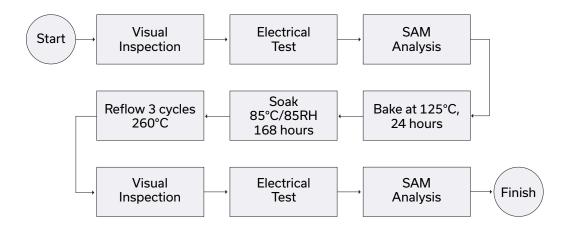
ESD RATING

Human Body Model (HBM): Class 1B (500<1000) in accordance with ANSI/ESD STM 5.1 - 2001 Machine Model (MM): Class class M1 (50V) in accordance with ANSI/ESD STM5.2-1999

MSL RATING

Moisture Sensitivity: MSL1 in accordance with IPC/JEDEC J-STD-020D

MSL TEST FLOW CHART



- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
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